

小信号快速开关二极管 Small Signal Fast Switching Diodes

■特征 Features

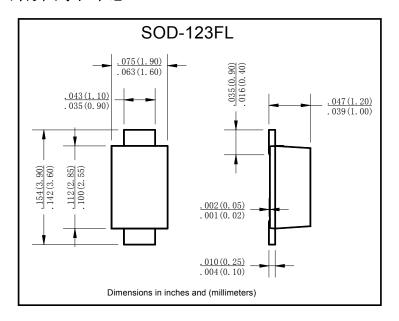
•V_R 75V

●I_{FAV} 150mA

■用途 Applications

●极端的快速开关 Extreme fast switches

■外形尺寸和印记 Outline Dimensions and Mark



■极限值(绝对最大额定值)

Limiting Values (Absolute Maximum Rating)

参数名称 Item	符号 Symbol	单位 Unit	条件 Conditions	最大值 Max
反向重复峰值电压 Repetitive peak reverse voltage	V_{RRM}	V		100
反向电压 Reverse voltage	V _R	V		75
正向浪涌峰值电流 Peak forward surge current	I _{FSM}	Α	t _p =1μs	4
正向重复峰值电流 Repetitive peak forward current	I _{FRM}	mA		500
正向持续电流 Forward continuous current	I _F	mA		300
正向平均电流 Average forward current	I _{FAV}	mA	V _R =0	150
功率消耗 Power dissipation	P _{tot}	mW	L=4mm,T _L =45℃	410
典型热阻 Thermal resistance	R _{thJA}	°C/W	结到环境 junction to ambient air	450
最大结温 Maximum junction temperature	T _j	$^{\circ}$		150
存储温度范围 Storage temperature range	T _{stg}	$^{\circ}$		-55 to +150



■电特性 (Ta=25°C 除非另有规定)

Electrical Characteristics (Ta=25°C Unless otherwise specified)

参数名称 Item	符号 Symbol	单位 Unit	条件 Conditions	最大值 Max
正向电压 Forward voltage	V _F	mV	I _F =0.15A	1.25
反向电流,T」 =25 ℃	I _R	μA	V _R =20V	0.025
Reverse current,T _J =25°C	IR IR		V _R =75V	2.5
击穿电压 Breakdown voltage	V _(BR)	V	I_R =100 μ A , t_p /T=0.01, t_p =0.3ms	100(min)
二极管电容 Diode capacitance	C _D	pF	V _R =0, f =1MH _Z , V _{HF} =50mV	4
反向恢复时间 Reverse recovery time	t _{rr}	ns	I _F = I _R =10mA , i _R =1mA	8
	trr		I_F = 10mA , V_R =6V , I_R =0.1× I_R , R_L =100 Ω	4

■特性曲线(典型) Characteristics(Typical)

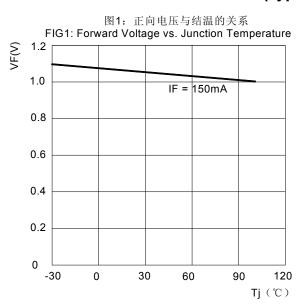


图2: 正向电流与正向电压的关系 FIG2: Forward Current vs. Forward Voltage 1000 1N4148 100 Scattering Limit 10 1.0 Tj=25℃ 0.1 0.4 8.0 1.6 2.0 1.2 VF(V)

图3: 反向电流与反向电压的关系 FIG3:Reverse Current vs. Reverse Voltage

